

L Number	Hits	Search Text	DB	Time stamp
2	273	analysis near3 (intrinsic adj charge or electric adj field\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:40
3	110	analysis near1 (intrinsic adj charge or electric adj field\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:26
4	4	small adj signal and analysis near1 intrinsic adj charge	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:27
5	20	small adj signal same analysis same characteristics	USPAT	2002/12/11 14:33
6	12	small adj signal same analysis same characteristics and semiconductor	USPAT	2002/12/11 14:34
-	0	small adj signal adj excitation adj analysis	USPAT	2002/12/11 14:31
-	4	small adj signal adj excitation adj analysis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 11:27
-	122	small adj signal adj model	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 11:51
-	7	semi adj physical adj model\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 12:00
-	7	(deriv\$3 or extract\$3) same circuit adj elements same (intrinsic adj charge or electric adj fields)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:38

12-11-02 Consulted primary ex Vuthe Art Unit 2825